

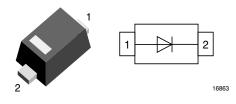
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RF PIN Diode - Single in SOD-523

Description

Characterized by low reverse Capacitance the PIN Diode BAR64V-02V was designed for RF signal switching and tuning. As a function of the forward bias current the forward resistance (rf) can be adjusted over a wide range. A long carrier life time offers low signal distortion for signals over 10 MHz up to 3 GHz. Typical applications for this PIN Diode are switches and attenuators in wireless, mobile and TVsystems.



Features

- High reverse Voltage
- Space saving SOD-523 package with low series inductance
- Small reverse capacitance
- High breakdown voltage
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

For frequency up to 3 GHz RF-signal tuning

Signal attenuator and switches Mobile, wireless and TV-Applications

Mechanical Data

Case: SOD-523 Plastic case Weight: approx. 1.6 mg Cathode Band Color: Laser marking Packaging Codes/Options: GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Parts Table

Part	Ordering code	Marking	Remarks
BAR64V-02V	BAR64V-02V-GS18 or BAR64V-02V-GS08	D	Tape and Reel

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

and				
Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V _R	100	V
Forward current		١ _F	100	mA
Junction temperature		Tj	150	°C
Storage temperature range		T _{stg}	- 55 to + 150	°C

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Thermal Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction soldering point		R _{thJS}	100	K/W

Electrical Characteristics

$T_{amb} = 25$ °C, unless otherwise specifie	= 25 °C, unless otherwise s	specified
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Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse voltage	I _R = 10 μA	V _R	100			V
Reverse current	V _R = 50 V	I _R			50	nA
Forward voltage	I _F = 50 mA	V _F			1.1	V
Diode capacitance	f = 1 MHz, V _R = 0	CD		0.5		pF
	f = 1 MHz, V _R = 1 V	CD		0.37	0.5	pF
	f = 1 MHz, V _R = 20 V	CD		0.23	0.35	pF
Forward resistance	f = 100 MHz, I _F = 1 mA	r _f		10	20	Ω
	f = 100 MHz, I _F = 10 mA	r _f		2.0	3.8	Ω
	f = 100 MHz, I _F = 100 mA	r _f		0.8	1.35	Ω
Charge carrier life time	$I_{\rm F} = 10 \text{ mA}, I_{\rm R} = 6 \text{ mA}, i_{\rm R} = 3 \text{ mA}$	t _{rr}		1.8		μs

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

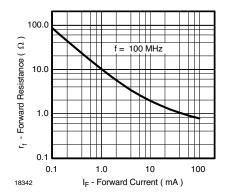


Figure 1. Forward Resistance vs. Forward Current

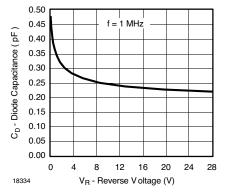


Figure 2. Diode Capacitance vs. Reverse Voltage



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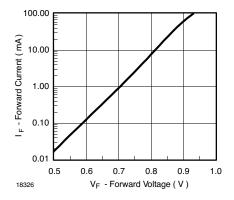


Figure 3. Forward Current vs. Forward Voltage

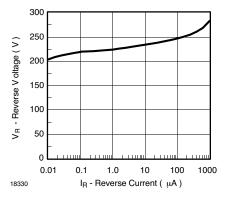


Figure 4. Reverse Voltage vs. Reverse Current

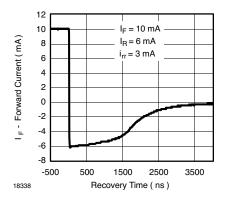
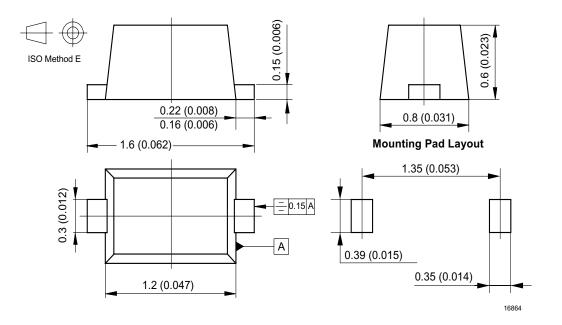


Figure 5. Typical Charge Recovery Curve

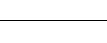
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Package Dimensions in mm (Inches)







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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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